

AMENDMENTS

In the Specification:

Amend the Title to read METHOD OF MANUFACTURING INSULATED GATE SEMICONDUCTOR DEVICE ~~AND MANUFACTURING METHOD THEREOF~~.

On the first page, after the Title, insert as the first paragraph of the specification the following new paragraph.

Reference to Related Applications:

This application is a division of Serial No. 09/925,628, filed August 10, 2001, now U.S.

Patent No. _____.